

LOW-POWER TRIPLE SCHMITT-TRIGGER BUFFER

Check for Samples: SN74AUP3G17

FEATURES

- Available in the Texas Instruments NanoStar™ Package
- Low Static-Power Consumption (I_{CC} = 0.9 μA Maximum)
- Low Dynamic-Power Consumption (C_{pd} = 4.3 pF Typ at 3.3 V)
- Low Input Capacitance (C_i = 1.5 pF Typical)
- Low Noise Overshoot and Undershoot <10% of V_{CC}
- I_{off} Supports Partial-Power-Down Mode Operation

1A □

3Y <u></u>

2A □

GND □

3

Wide Operating V_{CC} Range of 0.8 V to 3.6 V
 DCU PACKAGE

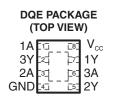
(TOP VIEW)

8 T V_{cc}

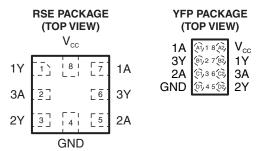
7 🖽 1Y

6 Ⅲ 3A

5



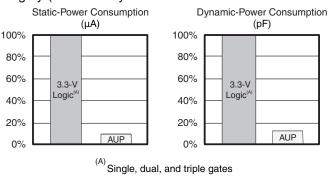
- Optimized for 3.3-V Operation
- 3.6-V I/O Tolerant to Support Mixed-Mode Signal Operation
- t_{pd} = 5.1 ns Maximum at 3.3 V
- Suitable for Point-to-Point Applications
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- ESD Performance Tested Per JESD 22
 - 2000-V Human-Body Model (A114-B, Class II)
 - 1000-V Charged-Device Model (C101)

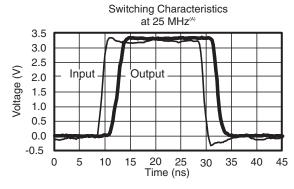


See mechanical drawings for dimensions.

DESCRIPTION/ORDERING INFORMATION

The AUP family is TI's premier solution to the industry's low-power needs in battery-powered portable applications. This family ensures a very low static- and dynamic-power consumption across the entire V_{CC} range of 0.8 V to 3.6 V, resulting in increased battery life (see Figure 1). This product also maintains excellent signal integrity (see the very low undershoot and overshoot characteristics shown in Figure 2).





 $^{(A)}$ SN74AUP3Gxx data at C_I = 15 pF.

Figure 1. AUP - The Lowest-Power Family

Figure 2. Excellent Signal Integrity

A

Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



The SN74LVC3G17 contains three buffers and performs the Boolean function Y = A. The device functions as three independent buffers but, because of Schmitt action, it may have different input threshold levels for positive-going (V_{T_+}) and negative-going (V_{T_-}) signals.

NanoStar™ package technology is a major breakthrough in IC packaging concepts, using the die as the package.

This device is fully specified for partial-power-down applications using I_{off} . The I_{off} circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

ORDERING INFORMATION(1)

T _A	PACKAGE ⁽²⁾		ORDERABLE PART NUMBER	TOP-SIDE Marking ⁽³⁾
	NanoStar [™] – WCSP (DSBGA) 0.23-mm Large Bump – YFP (Pb-free)	Reel of 3000	SN74AUP3G17YFPR	H7_
-40°C to 85°C	uQFN – DQE	Reel of 5000	SN74AUP3G17DQER	TY
	QFN - RSE	Reel of 5000	SN74AUP3G17RSER	PREVIEW
	SSOP - DCU	Reel of 3000	SN74AUP3G17DCUR	H17_

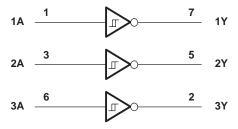
- (1) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI web site at www.ti.com.
- (2) Package drawings, thermal data, and symbolization are available at www.ti.com/packaging.
- (3) DCU: The actual top-side marking has one additional character that designates the wafer fab/assembly site.

 YFP: The actual top-side marking has three preceding characters to denote year, month, and sequence code, and one following character to designate the wafer fab/assembly site. Pin 1 identifier indicates solder-bump composition (1 = SnPb, = Pb-free).

FUNCTION TABLE

INPUT A	OUTPUT Y
Н	Н
L,	L

LOGIC DIAGRAM (POSITIVE LOGIC)



Pin numbers shown are for the DCU and DQE packages.



ABSOLUTE MAXIMUM RATINGS(1)

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V _{CC}	Supply voltage range	Supply voltage range			V
VI	Input voltage range ⁽²⁾		-0.5	4.6	V
Vo	Voltage range applied to any output in the h	high-impedance or power-off state ⁽²⁾	-0.5	4.6	V
Vo	Output voltage range in the high or low stat	te ⁽²⁾	-0.5	V _{CC} + 0.5	V
I _{IK}	Input clamp current	V ₁ < 0		-50	mA
I _{OK}	Output clamp current	V _O < 0		-50	mA
Io	Continuous output current			±20	mA
	Continuous current through V _{CC} or GND			±50	mA
		DCU package		220	
0	Deal - 1 (3)	DQE package		261	00044
θ_{JA}	Package thermal impedance ⁽³⁾	RSE package			°C/W
		YFP package		132	
T _{stg}	Storage temperature range	,	-65	150	°C

⁽¹⁾ Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

⁽²⁾ The input negative-voltage and output voltage ratings may be exceeded if the input and output current ratings are observed.

⁽³⁾ The package thermal impedance is calculated in accordance with JESD 51-7.



RECOMMENDED OPERATING CONDITIONS(1)

			MIN	MAX	UNIT	
V _{CC}	Supply voltage		0.8	3.6	V	
VI	Input voltage		0	3.6	V	
Vo	Output voltage		0	V_{CC}	V	
		V _{CC} = 0.8 V		-20	μΑ	
		V _{CC} = 1.1 V		-1.1		
	High-level output current	V _{CC} = 1.4 V		-1.7		
I _{OH}		V _{CC} = 1.65		-1.9	mA	
		V _{CC} = 2.3 V		-3.1		
		V _{CC} = 3 V		-4		
		V _{CC} = 0.8 V		20	μΑ	
		V _{CC} = 1.1 V		1.1		
	Lavidaval autout avenuet	V _{CC} = 1.4 V		1.7		
l _{OL}	Low-level output current	V _{CC} = 1.65 V		1.9	mA	
		V _{CC} = 2.3 V		3.1		
		V _{CC} = 3 V		4		
Δt/Δν	Input transition rise or fall rate	V _{CC} = 0.8 V to 3.6 V		200	ns/V	
T _A	Operating free-air temperature		-40	85	°C	

⁽¹⁾ All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.



ELECTRICAL CHARACTERISTICS

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	V	T _A	= 25°C	$T_A = -40$ °C	to 85°C	UNIT	
FARAMETER	TEST CONDITIONS	V _{CC}	MIN	TYP MAX	MIN	MAX	<u> </u>	
		0.8 V	0.3	0.6	0.3	0.6		
<i>I</i> _		1.1 V	0.53	0.9	0.53	0.9		
/ _{T+} Positive-going		1.4 V	0.74	1.11	0.74	1.11	V	
nput threshold		1.65 V	0.91	1.29	0.91	1.29	V	
oltage		2.3 V	1.37	1.77	1.37	1.77		
		3 V	1.88	2.29	1.88	2.29		
		0.8 V	0.1	0.6	0.1	0.6		
,		1.1 V	0.26	0.65	0.26	0.65		
T- egative-going		1.4 V	0.39	0.75	0.39	0.75	.,	
input threshold		1.65 V	0.47	0.84	0.47	0.84	V	
oltage		2.3 V	0.69	1.04	0.69	1.04		
		3 V	0.88	1.24	0.88	1.24		
		0.8 V	0.07	0.5	0.07	0.5		
		1.1 V	0.08	0.46	0.08	0.46		
V_{T}		1.4 V	0.18	0.56	0.18	0.56	V	
lysteresis		1.65 V	0.27	0.66	0.27	0.66		
$V_{T+} - V_{T-}$		2.3 V	0.53	0.92	0.53	0.92		
		3 V	0.79	1.31	0.79	1.31		
	I _{OH} = -20 μA	0.8 V to 3.6 V	V _{CC} - 0.1		V _{CC} - 0.1			
	I _{OH} = -1.1 mA	1.1 V	0.75 × V _{CC}		0.7 × V _{CC}			
	$I_{OH} = -1.7 \text{ mA}$	1.4 V	1.11		1.03			
	$I_{OH} = -1.9 \text{ mA}$	1.65 V	1.32		1.3			
′он	$I_{OH} = -2.3 \text{ mA}$		2.05		1.97		V	
	I _{OH} = -3.1 mA	2.3 V	1.9		1.85			
	$I_{OH} = -2.7 \text{ mA}$		2.72		2.67			
	$I_{OH} = -4 \text{ mA}$	3 V	2.6		2.55			
	$I_{OL} = 20 \mu\text{A}$	0.8 V to 3.6 V	2.0	0.1	2.00	0.1		
	$I_{OL} = 1.1 \text{ mA}$	1.1 V		0.3 × V _{CC}		0.3 × V _{CC}		
	I _{OL} = 1.7 mA	1.4 V		0.31		0.37		
	I _{OL} = 1.9 mA	1.65 V		0.31		0.35		
OL.	$I_{OL} = 2.3 \text{ mA}$	1.05 V		0.31		0.33	V	
	I _{OL} = 3.1 mA	2.3 V		0.44		0.45		
	$I_{OL} = 2.7 \text{ mA}$			0.31		0.43		
	$I_{OL} = 4 \text{ mA}$	3 V		0.44		0.45		
A or B input	~-	0 V to 3.6 V		0.1		0.45		
	$V_1 = 0.00 \text{ to } 3.6 \text{ V}$	0 V		0.1		0.6	μA μA	
off	$V_1 \text{ or } V_0 = 0 \text{ V to } 3.6 \text{ V}$	0 V to 0.2 V		0.2		0.6	μA	
l _{off}	$V_1 = GND \text{ or}$	0 V 10 0.2 V		0.2		0.0	μΑ	
CC	V _I = GND of (V _{CC} to 3.6 V), I _O = 0	0.8 V to 3.6 V		0.5		0.9	μΑ	
ulcc	$V_I = V_{CC} - 0.6 V^{(1)},$ $I_O = 0$	3.3 V		40		50	μΑ	
P _i	V _I = V _{CC} or GND	0 V 3.6 V		1.5 1.5			pF	
· '0	V _O = GND	0 V		3			pF	

⁽¹⁾ One input at V_{CC} – 0.6 V, other input at V_{CC} or GND



SWITCHING CHARACTERISTICS

over recommended operating free-air temperature range, $C_L = 5 pF$ (unless otherwise noted) (see Figure 3 and Figure 4)

PARAMETER	FROM	то	V	T _A	= 25°C		$T_A = -40^{\circ}C$	to 85°C	UNIT
PARAMETER	(INPUT)	(OUTPUT)	V _{CC}	MIN	TYP	MAX	M IN	MAX	UNIT
			0.8 V		22.7				
			1.2 V ± 0.1 V	6.3	8	12.8	3.9	14.6	
4	Α		1.5 V ± 0.1 V	4.6	5.8	8.4	2.8	10	no
t _{pd}	A	Y	1.8 V ± 0.15 V	3.9	4.8	7.2	2.4	8.1	ns
			2.5 V ± 0.2 V	3.1	3.6	5.1	2	6.1	
			3.3 V ± 0.3 V	2.7	3	4.4	1.9	5.1	

SWITCHING CHARACTERISTICS

over recommended operating free-air temperature range, C_L = 10 pF (unless otherwise noted) (see Figure 3 and Figure 4)

PARAMETER	FROM	то	V	T _A	= 25°C	;	T _A = -40°C	to 85°C	UNIT				
PARAMETER	(INPUT)	(OUTPUT)	V _{CC}	MIN	TYP	MAX	MIN	MAX	UNIT				
			0.8 V		25.1								
		Y	1.2 V ± 0.1 V	7.1	9.1	13.8	4.7	15.6					
	Δ.		Y	V	V	V	1.5 V ± 0.1 V	5.2	6.5	9.4	3.4	11	20
t _{pd}	Α			1.8 V ± 0.15 V	4.5	5.4	8	2.9	9	ns			
			2.5 V ± 0.2 V	3.5	4.2	5.7	2.4	6.8					
			3.3 V ± 0.3 V	3.1	3.5	4.9	2.2	5.7					

SWITCHING CHARACTERISTICS

over recommended operating free-air temperature range, $C_L = 15 \text{ pF}$ (unless otherwise noted) (see Figure 3 and Figure 4)

PARAMETER	FROM	то	V _{CC}	T _A	= 25°C		$T_A = -40$ °C to	o 85°C	UNIT			
PARAMETER	(INPUT)	(OUTPUT)		MIN	TYP	MAX	MIN	MAX	UNIT			
			0.8 V		27.6							
			1.2 V ± 0.1 V	7.8	10.1	14.8	5.3	16.7				
4	Α	۸	V	V	Υ	1.5 V ± 0.1 V	5.8	7.4	10.3	3.9	12	no
t _{pd}	A	ī	1.8 V ± 0.15 V	5	6.1	8.8	3.4	10	ns			
			2.5 V ± 0.2 V	4	4.7	6.4	2.8	7.5				
			3.3 V ± 0.3 V	3.5	4.1	5.4	2.6	6.2				

SWITCHING CHARACTERISTICS

over recommended operating free-air temperature range, C_L = 30 pF (unless otherwise noted) (see Figure 3 and Figure 4)

DADAMETED	FROM	то	V	T,	λ = 25°C	;	T _A = -40°C t	o 85°C	LINUT
PARAMETER	(INPUT)	(OUTPUT)	V _{CC}	MIN	TYP	MAX	MIN	MAX	UNIT
			0.8 V		35.1				
			1.2 V ± 0.1 V	10	13.1	18.1	7.5	19.8	
	Α		1.5 V ± 0.1 V	7.4	9.6	12.9	5.6	14.9	ns
t _{pd}	^	ı	1.8 V ± 0.15 V	6.4	7.9	11	4.8	12.4	115
			2.5 V ± 0.2 V	5.2	6.1	8.1	4	9.3	
			3.3 V ± 0.3 V	4.6	5.3	6.9	3.6	7.7	

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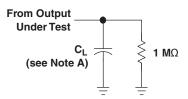
OPERATING CHARACTERISTICS

 $T_A = 25$ °C

	PARAMETER	TEST CONDITIONS	V _{CC}	TYP	UNIT
			0.8 V	4	
	C. Bauca dissination considers		1.2 V ± 0.1 V	4	
_		f = 10 MHz	1.5 V ± 0.1 V	4	
C _{pd}	Power dissipation capacitance		1.8 V ± 0.15 V	4	pF
			2.5 V ± 0.2 V	4.1	
			3.3 V ± 0.3 V	4.3	

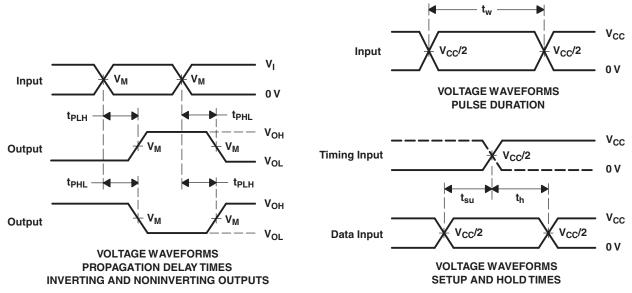


PARAMETER MEASUREMENT INFORMATION (Propagation Delays, Setup and Hold Times, and Pulse Width)



LOAD CIRCUIT

	V _{CC} = 0.8 V	V _{CC} = 1.2 V ± 0.1 V	V _{CC} = 1.5 V ± 0.1 V	V_{CC} = 1.8 V \pm 0.15 V	V_{CC} = 2.5 V \pm 0.2 V	V _{CC} = 3.3 V ± 0.3 V
C _L	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF
V _M	V _{CC} /2	V _{CC} /2	V _{CC} /2	V _{CC} /2	V _{CC} /2	V _{CC} /2
V _I	V _{CC}	V _{CC}	V _{CC}	V _{CC}	V _{CC}	V _{CC}



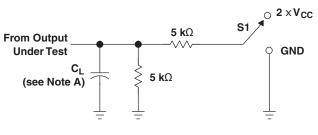
- A. C_L includes probe and jig capacitance.
- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_O = 50 \Omega$, for propagation delays $t_t/t_f = 3$ ns, for setup and hold times and pulse width $t_t/t_f = 1.2$ ns.
- D. The outputs are measured one at a time, with one transition per measurement.
- E. t_{PLH} and t_{PHL} are the same as t_{pd} .
- F. All parameters and waveforms are not applicable to all devices.

Figure 3. Load Circuit and Voltage Waveforms

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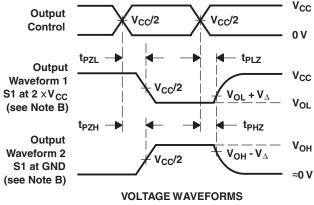
PARAMETER MEASUREMENT INFORMATION (Enable and Disable Times)



TEST	S1
t _{PLZ} /t _{PZL}	2 × V _{CC}
t _{PHZ} /t _{PZH}	GND

LOAD CIRCUIT

	V _{CC} = 0.8 V	V _{CC} = 1.2 V ± 0.1 V	V _{CC} = 1.5 V ± 0.1 V	V_{CC} = 1.8 V \pm 0.15 V	V_{CC} = 2.5 V \pm 0.2 V	V_{CC} = 3.3 V \pm 0.3 V
$\begin{array}{c c} \textbf{C}_{\textbf{L}} & \\ \textbf{V}_{\textbf{M}} & \\ \textbf{V}_{\textbf{I}} & \\ \textbf{V}_{\boldsymbol{\Delta}} & \end{array}$	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF
	V _{CC} /2	V _{CC} /2	V _{CC} /2	V _{CC} /2	V _{CC} /2	V _{CC} /2
	V _{CC}	V _{CC}	V _{CC}	V _{CC}	V _{CC}	V _{CC}
	0.1 V	0.1 V	0.1 V	0.15 V	0.15 V	0.3 V



- ENABLE AND DISABLE TIMES LOW- AND HIGH-LEVEL ENABLING
- A. C_L includes probe and jig capacitance.
- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_O = 50 \ \Omega$, $t_r/t_f = 3 \ ns$.
- D. The outputs are measured one at a time, with one transition per measurement.
- E. t_{PLZ} and t_{PHZ} are the same as t_{dis} .
- F. t_{PLH} and t_{PHL} are the same as t_{pd}.
- G. All parameters and waveforms are not applicable to all devices.

Figure 4. Load Circuit and Voltage Waveforms

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PACKAGE OPTION ADDENDUM

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PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	e Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp (3)
SN74AUP3G17DCUR	ACTIVE	US8	DCU	8	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74AUP3G17DQER	PREVIEW	X2SON	DQE	8	5000	TBD	Call TI	Call TI
SN74AUP3G17YFPR	PREVIEW	DSBGA	YFP	8	3000	TBD	Call TI	Call TI

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

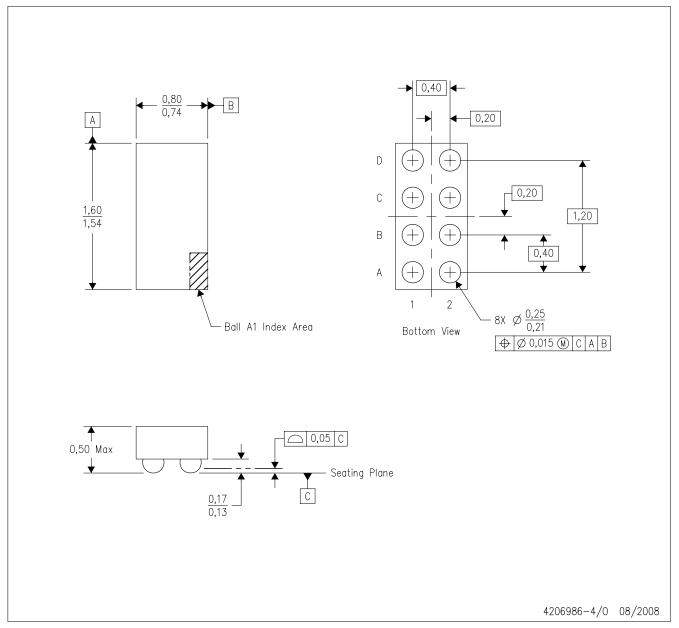
(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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YFP (R-XBGA-N8)

DIE-SIZE BALL GRID ARRAY



NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.

- B. This drawing is subject to change without notice.
- C. NanoFree™ package configuration.
- D. This is a Pb-free solder ball design.

NanoFree is a trademark of Texas Instruments.



DCU (R-PDSO-G8)

PLASTIC SMALL-OUTLINE PACKAGE (DIE DOWN)



NOTES:

- A. All linear dimensions are in millimeters.
 - B. This drawing is subject to change without notice.
 - C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
 - D. Falls within JEDEC MO-187 variation CA.



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